

Localization of Dirac fermions and metal-insulator transition in chiral systems

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in collaboration with

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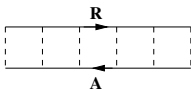
- 1 Introduction
- 2 From ballistics to diffusion
- 3 From diffusion to localization
- 4 Summary

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Symmetry Classification

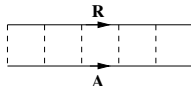
Wigner '51, Dyson '62, Altland and Zirnbauer '97, Schnyder et al '08

- Always present: diffuson



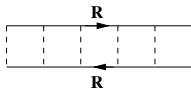
- Time-reversal symmetry (T):

$$H = UH^T U^{-1}, \quad T^2 = U U^* = \pm 1 \quad \text{Cooperon}$$



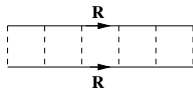
- Chiral symmetry (C):

$$H = -U H U^{-1} \quad \text{RR diffuson}$$



- Particle-hole symmetry (CT):

$$H = -U H^T U^{-1}, \quad C T^2 = U U^* = \pm 1 \quad \text{RR Cooperon}$$



Symmetry Classification

Wigner '51, Dyson '62, Altland and Zirnbauer '97, Schnyder et al '08

	T^2	C	CT^2	NL σ M	π_1	π_2	π_3	WL
A	0	0	0	$U(2N)/U(N) \times U(N)$	0	\mathbb{Z}	0	0(-)
AI	1	0	0	$Sp(2N)/Sp(N) \times Sp(N)$	0	0	0	-
AII	-1	0	0	$O(2N)/O(N) \times O(N)$	\mathbb{Z}_2	\mathbb{Z}_2	0	+
AIII	0	1	0	$U(N)$	\mathbb{Z}	0	\mathbb{Z}	$\equiv 0$
BDI	1	1	1	$U(2N)/Sp(2N)$	\mathbb{Z}	0	0	$\equiv 0$
CII	-1	1	-1	$U(N)/O(N)$	\mathbb{Z}	\mathbb{Z}_2	\mathbb{Z}_2	$\equiv 0$
D	0	0	1	$O(2N)/U(N)$	0	\mathbb{Z}	0	+
C	0	0	-1	$Sp(2N)/U(N)$	0	\mathbb{Z}	\mathbb{Z}_2	-
DIII	-1	1	1	$O(N)$	\mathbb{Z}_2	0	\mathbb{Z}	+
CI	1	1	-1	$Sp(2N)$	0	0	\mathbb{Z}	-

Classification: Bott periodicity

Kitaev '08, Schnyder et al '08

	T^2	C	CT^2	NL σ M	π_1	π_2	π_3	π_4
A	0	0	0	$U(2N)/U(N) \times U(N)$	0	\mathbb{Z}	0	\mathbb{Z}
AIII	0	1	0	$U(N)$	\mathbb{Z}	0	\mathbb{Z}	0
AI	1	0	0	$Sp(2N)/Sp(N) \times Sp(N)$	0	0	0	\mathbb{Z}
BDI	1	1	1	$U(2N)/Sp(2N)$	\mathbb{Z}	0	0	0
D	0	0	1	$O(2N)/U(N)$	0	\mathbb{Z}	0	0
DIII	-1	1	1	$O(N)$	\mathbb{Z}_2	0	\mathbb{Z}	0
Alt	-1	0	0	$O(2N)/O(N) \times O(N)$	\mathbb{Z}_2	\mathbb{Z}_2	0	\mathbb{Z}
CII	-1	1	-1	$U(N)/O(N)$	\mathbb{Z}	\mathbb{Z}_2	\mathbb{Z}_2	0
C	0	0	-1	$Sp(2N)/U(N)$	0	\mathbb{Z}	\mathbb{Z}_2	\mathbb{Z}_2
CI	1	1	-1	$Sp(2N)$	0	0	\mathbb{Z}	\mathbb{Z}_2

Classification of topological insulators

Kitaev '08, Schnyder et al '08

\mathbb{Z} topology

Let $\pi_d = \mathbb{Z}$ (as in QHE at $d = 2$)

\implies topological term may appear in d dimensions

\implies $(d - 1)$ -dimensional surface states delocalized

\implies **d -dimensional \mathbb{Z} topological insulator**

\mathbb{Z}_2 topology

Let $\pi_d = \mathbb{Z}_2$ (as on the $d = 2$ surface of 3D BiSb)

\implies topological term with $\theta = \pi$

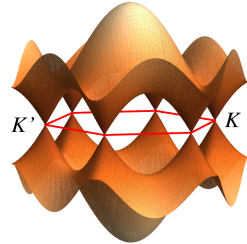
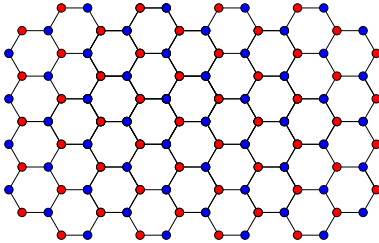
\implies absence of localization (as in graphene with potential disorder)

\implies **$(d + 1)$ -dimensional \mathbb{Z}_2 topological insulator**

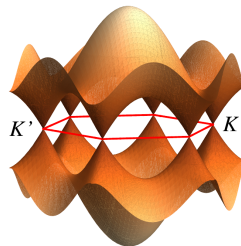
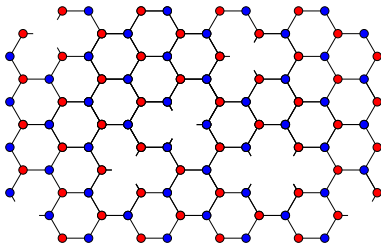
Classification of topological insulators

Kitaev '08, Schnyder et al '08

	T^2	C	CT^2	$1D$	$2D$	$3D$	$4D$
A	0	0	0	0	\mathbb{Z}	0	\mathbb{Z}
AIII	0	1	0	\mathbb{Z}	0	\mathbb{Z}	0
AI	1	0	0	0	0	0	\mathbb{Z}
BDI	1	1	1	\mathbb{Z}	0	0	0
D	0	0	1	\mathbb{Z}_2	\mathbb{Z}	0	0
DIII	-1	1	1	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}	0
AII	-1	0	0	0	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}
CII	-1	1	-1	\mathbb{Z}	0	\mathbb{Z}_2	\mathbb{Z}_2
C	0	0	-1	0	\mathbb{Z}	0	\mathbb{Z}_2
CI	1	1	-1	0	0	\mathbb{Z}	0



- Chiral structure: two sublattices: A, B
- Two valleys of the spectrum: K, K'
- linear dispersion: $\varepsilon = v_0 |\mathbf{p}|$
- Massless Dirac Hamiltonian in each valley: $H = v_0 \boldsymbol{\sigma} \mathbf{p}$, $\boldsymbol{\sigma} = \{\sigma_x, \sigma_y\}$
- Vacancies preserve chiral symmetry (class BDI)



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- **Vacancies preserve chiral symmetry (class BDI)**

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- Matrix Green function [Nazarov '94]

$$\check{G} = \begin{pmatrix} \epsilon + i0 - H & -\delta(x)v_x \sin \frac{\phi}{2} \\ -\delta(x-L)v_x \sin \frac{\phi}{2} & \epsilon - i0 - H \end{pmatrix}^{-1}$$

- Generating function (free energy): $\mathcal{F}(\phi) = \text{Tr} \log \check{G}^{-1}(\phi)$

$$\implies \text{Conductance: } G = -\frac{2e^2}{h} \left. \frac{\partial^2 \mathcal{F}}{\partial \phi^2} \right|_{\phi=0}$$

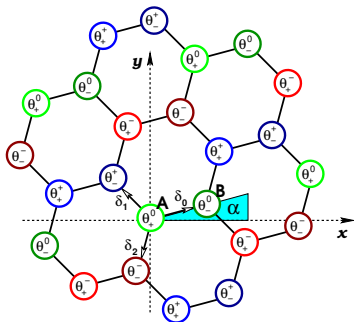
$$\implies \text{Fano factor: } F = \frac{1}{3} - \frac{2}{3} \left. \frac{\partial^4 \mathcal{F} / \partial \phi^4}{\partial^2 \mathcal{F} / \partial \phi^2} \right|_{\phi=0}$$

- Clean graphene

$$\mathcal{F}_0(\phi) = -\frac{W\phi^2}{\pi L}, \quad G = \frac{4e^2}{\pi h} \frac{W}{L}, \quad F = \frac{1}{3}$$

On-site potential

- From lattice to Dirac: $\Psi_i = \langle u_i | \Phi(\mathbf{r}) \rangle$
 $|\Phi(\mathbf{r})\rangle$ – smooth envelope function (Dirac Hamiltonian)
 Bloch function $\langle u_i | = \begin{cases} (e^{i\theta_+/2}, 0, 0, e^{-i\theta_+/2}), & \mathbf{r}_i \in A, \\ (0, ie^{i\theta_-/2}, ie^{-i\theta_-/2}, 0), & \mathbf{r}_i \in B. \end{cases}$
- On-site potential in the Dirac language: $|u_i\rangle V_i \langle u_i|$



Phases θ_{\pm} depend on sublattice and “color” of the site:

$$\theta_{\pm} = \pm\alpha + 2\mathbf{K} \cdot \mathbf{r}_i = \pm\alpha + 2\pi ic/3$$

Color index: $c = 0, \pm 1$

- Generating function

$$\mathcal{F}(\phi) = \mathcal{F}_0 + \text{Tr} \log(1 - \check{G}_0 V) \quad \text{with} \quad V = \sum_m |u_m\rangle V(\mathbf{r}_m) \langle u_m|$$

- Unfolding: $\mathcal{F}(\phi) = \mathcal{F}_0 + \log \det [\delta_{nm} - V_n \langle u_n | \check{G}_0(\mathbf{r}_n, \mathbf{r}_m) | u_m \rangle]$
- Vacancies $V_n \rightarrow \infty$: $\mathcal{F}(\phi) = \mathcal{F}_0 + \log \det \langle u_n | \check{G}_0(\mathbf{r}_n, \mathbf{r}_m) | u_m \rangle$
- Conductance

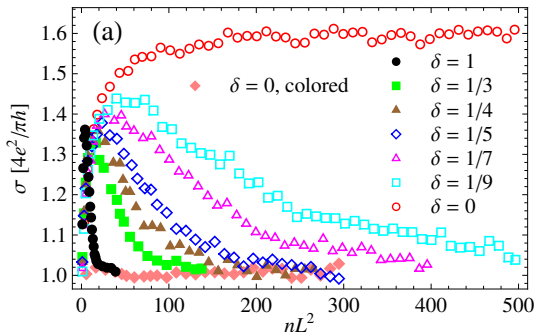
$$G = \frac{4e^2}{\pi h} \left\{ \frac{W}{L} + \pi \text{Tr} [K, Y] (K + K^T)^{-1} [K^T, Y] (K + K^T)^{-1} \right\}$$

$$K_{mn} = \frac{e^{i(\theta_m - \theta_n)}}{\sin \frac{\pi}{2L} [\zeta_m x_m + \zeta_n x_n + i(y_m - y_n)]}, \quad Y = L^{-1} \text{diag}\{y_n\}$$

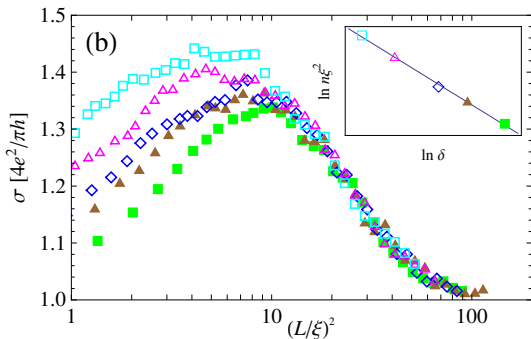
$\zeta_i = \pm 1$ and θ_i are sublattice and color of i th vacancy

Inversion of an $N \times N$ matrix \implies extremely efficient numerics!

Vacancies: numerics



- Single color, armchair boundary ($\alpha = 0$)
- Sublattice imbalance $\delta = (n_A - n_B)/n$
- Unstable fixed point for $\delta = 0$ (conductivity saturates at $\sigma \approx 2e^2/h$)
- Stable fixed point for $n_B \neq n_A$ with $\sigma \approx \frac{4e^2}{\pi h}$

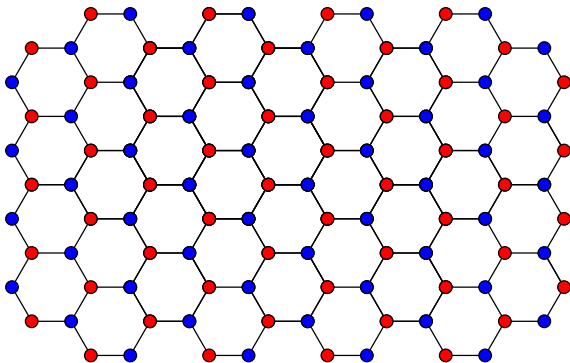


- Crossover curves collapse in units of L/ξ
- Power law scaling $n \xi^2 \sim \delta^{0.72}$

Novel strong-coupling criticality in class BDI beyond sigma model

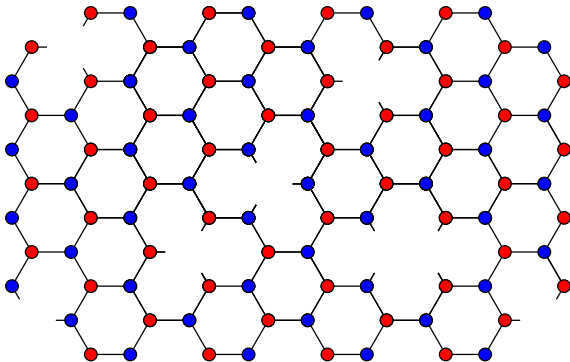
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From metal to insulator



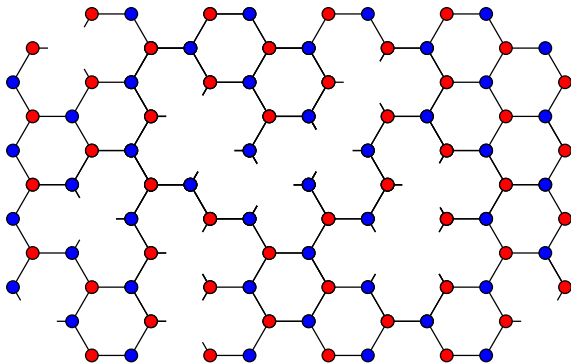
Gradually remove sites from graphene
Metal-insulator transition expected!

From metal to insulator



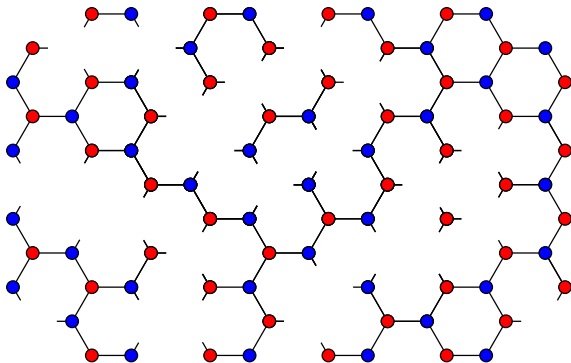
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From metal to insulator



Gradually remove sites from graphene
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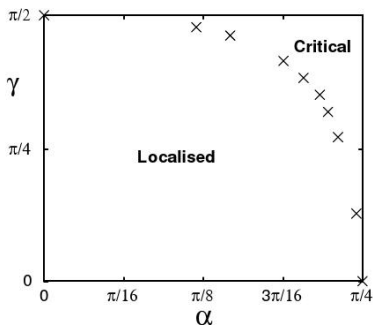
From metal to insulator



Gradually remove sites from graphene
Metal-insulator transition expected!

Numerics: Chiral Network Models

Bocquet and Chalker '03



- Chiral unitary (AIII) network model
- Both critical (Gade) and localized phase observed
- Similar results for dimerized lattice model [Motrunich *et al* '02]

Localization from metallic perspective

Gade and Wegner '91, Gade '93

- 2D nonlinear sigma model for a chiral system

$$S[Q] = \int d^2x \left\{ \frac{\sigma}{8\pi} \text{tr} [\nabla Q^{-1} \nabla Q] - \frac{c}{8\pi} [\text{tr} Q^{-1} \nabla Q]^2 \right\}$$

- Matrix field

$$Q \in \begin{cases} U(N), & \text{unitary (AIII)}, \\ U(N)/Sp(N), & \text{orthogonal (BDI)}, \\ U(N)/O(N), & \text{symplectic (CII)}. \end{cases}$$

- Replica limit $N \rightarrow 0$ is assumed
- σ – conductivity per square

Localization from metallic perspective

Gade and Wegner '91, Gade '93

- Rewrite $Q = e^{i\phi} U$ ($\det U = 1$)

$$S[U, \phi] = \int d^2x \left\{ \frac{\sigma}{8\pi} \text{tr} [\nabla U^{-1} \nabla U] + N \left(\frac{\sigma + Nc}{8\pi} \right) (\nabla \phi)^2 \right\}$$

- Decoupled Gaussian theory in ϕ :

$$\frac{d}{d \ln L} (\sigma + Nc) = 0$$

- Replica limit

$$\frac{d\sigma}{d \ln L} = -N \frac{dc}{d \ln L} \xrightarrow{N \rightarrow 0} 0$$

Absence of localization to all orders in perturbation theory!

Apparent controversy

- Strong disorder induces localization in a chiral system (intuition + numerics)
- No traces of localization in the perturbation theory in the metallic limit (Gade and Wegner)

How to resolve?

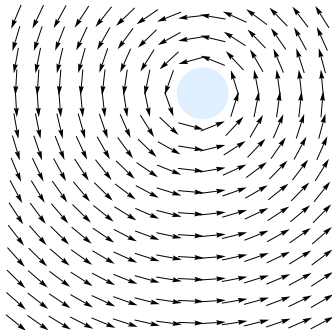
Take into account non-perturbative effects

Bypass Gade and Wegner argument

- Loophole to escape Gade and Wegner argument:

$$\det Q = e^{i\phi} \in U(1) \simeq \mathbb{S}^1$$

⇒ **vortex excitations allowed!**



- Recalls Berezinskii-Kosterlitz-Thouless transition!

BKT Transition

Berezinskii '70, Kosterlitz and Thouless '73

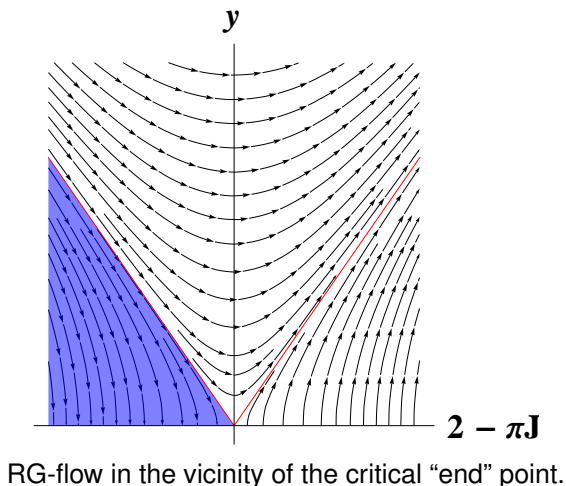
- Continuum limit of xy-model: $S[\phi] = \frac{J}{2} \int d^2x (\nabla\phi)^2$
- Vortex excitations with core energy S_{core}
- Large J (low temperature):
 - \implies vortices strongly bound in tiny dipoles
 - \implies ordered phase (quasi long-range order)
- Small J (high temperature):
 - \implies vortex plasma, disordered phase
- Renormalization group (fugacity $y = L^2 e^{-S_{\text{core}}}$)

$$\frac{dJ}{d \ln L} = -y^2 J^2$$

$$\frac{dy}{d \ln L} = (2 - \pi J) y$$

BKT Transition

Berezinskii '70, Kosterlitz and Thouless '73



- Bare action

$$S_0[Q] = \int d^2x \left\{ \frac{\sigma_0}{8\pi} \text{tr} [\nabla Q^{-1} \nabla Q] - \frac{c_0}{8\pi} [\text{tr} Q^{-1} \nabla Q]^2 \right\}$$

- Separate fast and slow variables $Q = U^{-1} \tilde{Q} V$
 \tilde{Q} – fast; U, V – slow
- Integrate out fast variables
- Sigma-model action for slow $Q' = U^{-1} V$ with corrected constants

- Expand the fast field \tilde{Q} near 1

\implies One-loop perturbative RG:

$$\frac{d\sigma}{d \ln L} = 0, \quad \frac{dc}{d \ln L} = 1$$

Exact in All class [Guruswamy *et al* '00]

- Include one vortex-antivortex dipole in \tilde{Q}
(lowest order in fugacity $y = L^2 e^{-S_{\text{core}}}$)

$$\frac{d\sigma}{d \ln L} = -\sigma y^2,$$

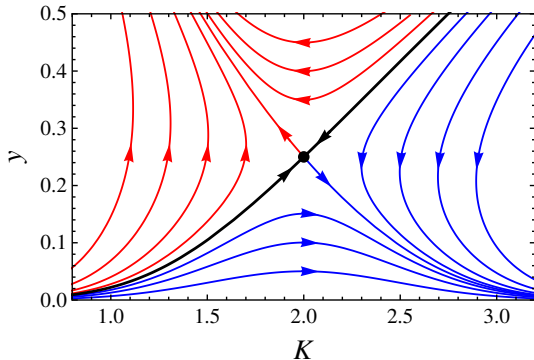
$$\frac{dc}{d \ln L} = 1 - (\sigma + 2c)y^2,$$

$$\frac{dy}{d \ln L} = \left(2 - \frac{\sigma + c}{4}\right) y$$

Flow diagram

In terms of stiffness parameter $K = (\sigma + c)/4$

$$\frac{d\sigma}{d \ln L} = -\sigma y^2, \quad \frac{dK}{d \ln L} = \frac{1}{4} - 2Ky^2, \quad \frac{dy}{d \ln L} = (2 - K)y$$



Fixed points:

- metal (Gade)
- critical
- insulator

No minimal metallic conductivity

- Chiral symplectic class CII admits \mathbb{Z}_2 θ -term
 - ⇒ Vortices attract instantons
 - ⇒ Vortex-instanton fusion changes $S_{\text{core}} \mapsto S_{\text{core}} + i\pi$
 - ⇒ Internal \mathbb{Z}_2 degree of freedom in each vortex
- Chiral unitary class AIII admits **Wess-Zumino term**
 - ⇒ Vortices break global gauge symmetry
 - ⇒ Internal “Goldstone” degree of freedom in each vortex
 - ⇒ Random $\text{Im } S_{\text{core}}$

Presence of topological terms in sigma-model action prevents the theory from vortices!

Ballistics \leftrightarrow Diffusion

- 1 Efficient approach to studying transport in strongly disordered systems is developed
- 2 The theory is applied to graphene with vacancies
- 3 Various novel strong-coupling critical regimes are identified

Diffusion \leftrightarrow Localization

- 1 Renormalization of sigma model due to vortices
- 2 Non-perturbative weak localization correction in chiral systems
- 3 Topological prevention of vortex-induced localization

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